

PMDPB30XN 20 V, dual N-channel Trench MOSFET 6 July 2012

Product data sheet

Product profile 1.

1.1 General description

Dual N-channel enhancement mode Field-Effect Transistor (FET) in a small and leadless ultra thin DFN2020-6 (SOT1118) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- Very fast switching •
- Trench MOSFET technology
- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- Exposed drain pad for excellent thermal conduction

1.3 Applications

- Charging switch for portable devices
- DC-to-DC converters
- Small brushless DC motor drive
- Power management in battery-driven portables
- Hard disc and computing power management

1.4 Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Per transistor					·	·	
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	20	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	5.3	А
Static charact	eristics (per transistor)						
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 3 A; T _j = 25 °C		-	32	40	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².



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2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source TR1	6 5 4	D1 D2
2	G1	gate TR1		
3	D2	drain TR2	7 8	
4	S2	source TR2		
5	G2	gate TR2		G1 S1 S2 G2
6	D1	drain TR1	Transparent top view DFN2020-6 (SOT1118)	017aaa254
7	D1	drain TR1	21112020 3 (0011110)	
8	D2	drain TR2		

3. Ordering information

Table 3. Ordering in	formation		
Type number Package			
	Name	Description	Version
PMDPB30XN	DFN2020-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1118

4. Marking

Table 4. Marking codes	
Type number	Marking code
PMDPB30XN	1V

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
Per transis	tor					
V _{DS}	drain-source voltage	T _j = 25 °C		-	20	V
V _{GS}	gate-source voltage			-12	12	V
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	5.3	А
		V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	4	А
		V _{GS} = 4.5 V; T _{amb} = 100 °C	[1]	-	2.6	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	12	А
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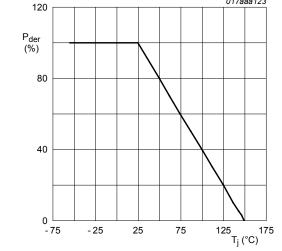
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Symbol	Parameter	Conditions		Min	Мах	Unit
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	490	mW
			[1]	-	1170	mW
		T _{sp} = 25 °C		-	8330	mW
Source-drai	in diode		· ·		1	
I _S	source current	T _{amb} = 25 °C	[1]	-	1.2	А
Per device			'			
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².
Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.







$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

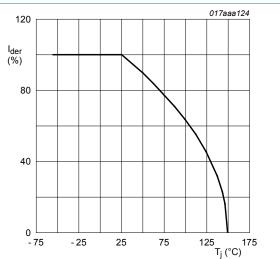
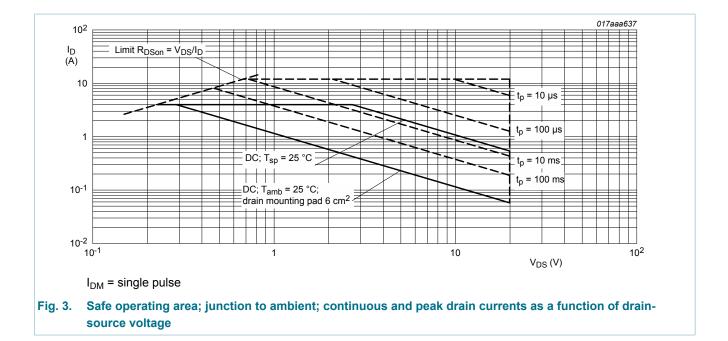


Fig. 2. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^\circ\text{C})}} \times 100 \ \%$$

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6. Thermal characteristics

Table 6. Th	ermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transisto	r						
- ui(j-a)	thermal resistance	in free air	[1]	-	223	256	K/W
	from junction to		[2]	-	93	107	K/W
	ampient	in free air; t ≤ 5 s	[2]	-	55	63	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	10	15	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

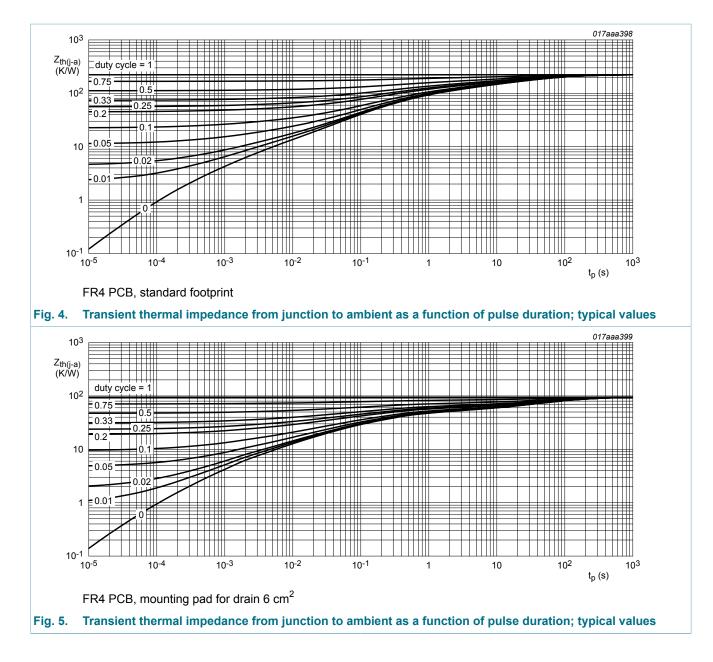
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

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7. Characteristics

Table 7. Ch	naracteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static characteristics (per transistor)							
V _{(BR)DSS}	drain-source breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C		20	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS} ; T_j = 25 °C		0.4	0.65	0.9	V
I _{DSS}	drain leakage current	V_{DS} = 20 V; V_{GS} = 0 V; T_j = 25 °C		-	-	1	μA
		V _{DS} = 20 V; V _{GS} = 0 V; T _j = 150 °C		-	-	11	μA
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{GSS} gate leakage current	gate leakage current	V_{GS} = 12 V; V_{DS} = 0 V; T_j = 25 °C	-	-	100	nA
		V_{GS} = -12 V; V_{DS} = 0 V; T_j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state	V_{GS} = 4.5 V; I _D = 3 A; T _j = 25 °C	-	32	40	mΩ
	resistance	V _{GS} = 4.5 V; I _D = 3 A; T _j = 150 °C	-	55	69	mΩ
		V _{GS} = 2.5 V; I _D = 1.4 A; T _j = 25 °C	-	40	53	mΩ
		V _{GS} = 1.8 V; I _D = 1.4 A; T _j = 25 °C	-	60	75	mΩ
9fs	forward transconductance	V _{DS} = 5 V; I _D = 3 A; T _j = 25 °C	-	12	-	S
Dynamic cl	naracteristics (per transist	tor)	1			
Q _{G(tot)}	total gate charge	V_{DS} = 10 V; I _D = 3 A; V _{GS} = 4.5 V;	-	14.4	21.7	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1.1	-	nC
Q _{GD}	gate-drain charge		-	1.5	-	nC
C _{iss}	input capacitance	V_{DS} = 10 V; f = 1 MHz; V_{GS} = 0 V;	-	660	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	87	-	pF
C _{rss}	reverse transfer capacitance		-	74	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 10 V; I _D = 3 A; V _{GS} = 4.5 V;	-	4	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	15	-	ns
t _{d(off)}	turn-off delay time		-	40	-	ns
				16		

Source-drain diode (per transist

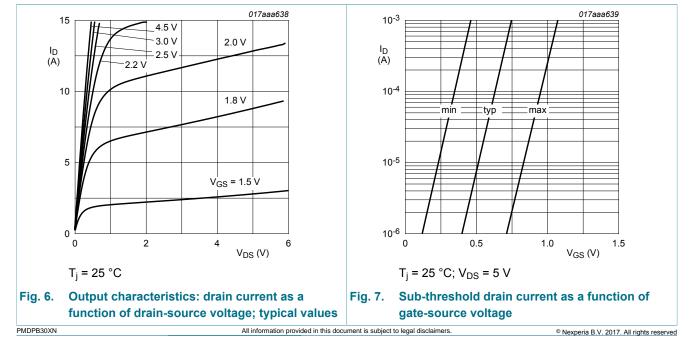
 V_{SD}

source-drain voltage I_{S} = 1.2 A; V_{GS} = 0 V; T_{j} = 25 °C

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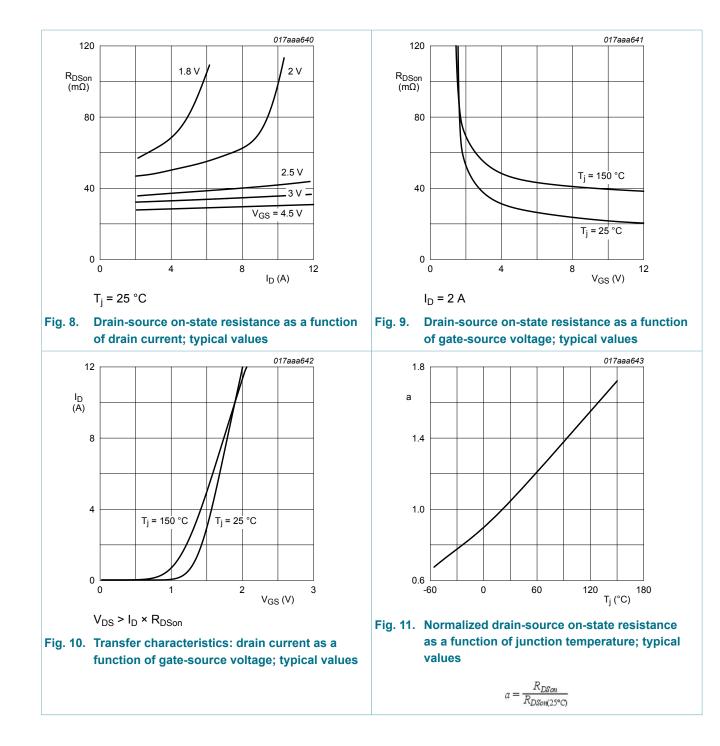
1.2 V

0.8



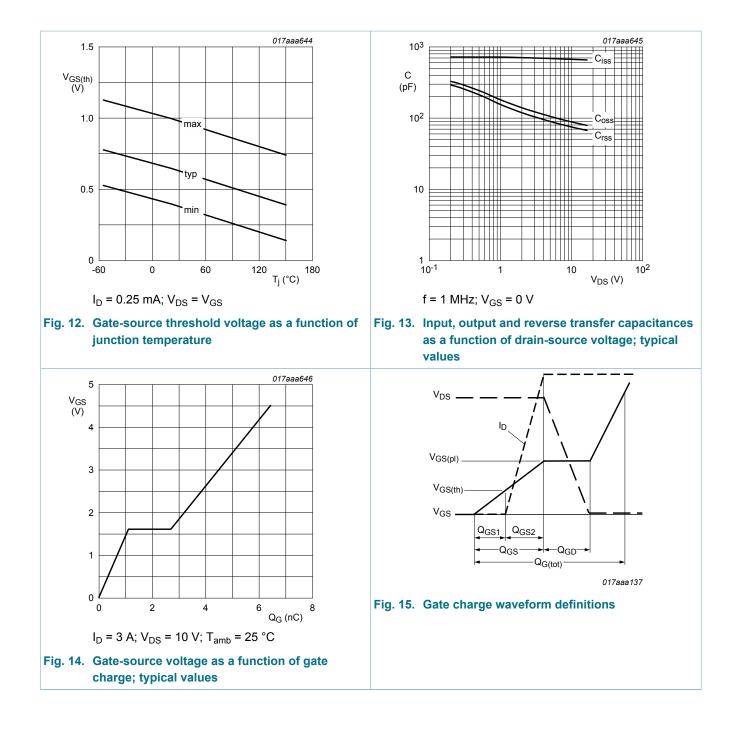
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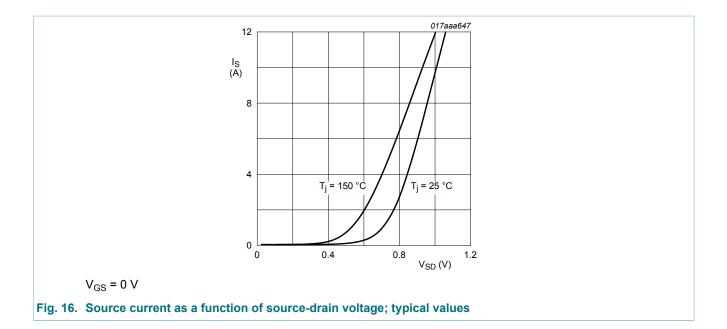
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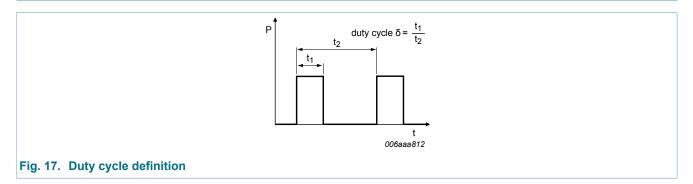


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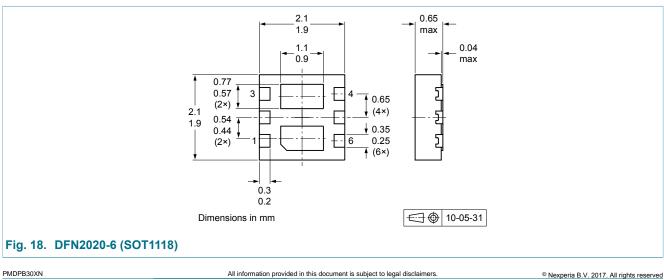
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8. Test information

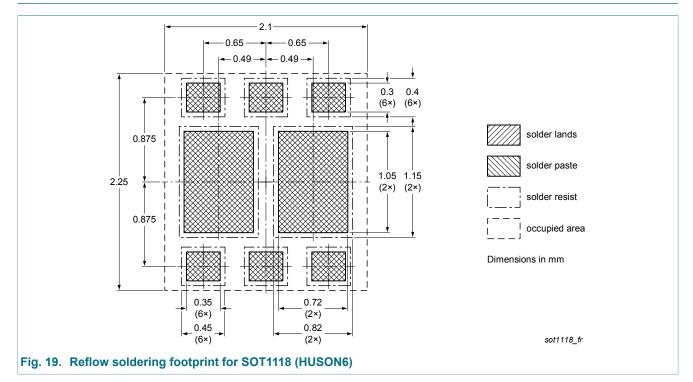


9. Package outline



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10. Soldering



11. Revision history

Table 8. Revision history					
Document ID	Release date	Document status	Change notice	Supersedes	
PMDPB30XN v.1	20120706	Product data sheet	-	-	

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12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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